

# 數位電路設計

## Lab3 – 同步循序電路之 HDL 模組撰寫與測試

### 1. 目標(Goal)

在這次 Lab 中，我們希望同學們可以熟悉 Latch、正反器、同步循序電路的設計原理。以 **state-diagram-based model** 與 **structural model** 等不同方式撰寫同步循序電路之 Verilog HDL 電路模組，並撰寫測試模組。分別模擬後，繳交模組檔案與波形圖。

The main purpose of this Lab Unit is to be familiar with the design of latch, flip-flop, and synchronous sequential circuit. Please write the Verilog HDL circuit modules of synchronous sequential circuits by state-diagram-base model and structural model, and write the testbench for these circuit modules. After simulation, upload the files of the modules and the waveforms of the simulation results.

### 2. 撰寫 HDL 電路模組與測試模組(Design of the HDL Circuit Modules and Testbench)

A.  **$\bar{S}\bar{R}$ -Latch**: 下圖為一  $\bar{S}\bar{R}$ -Latch 的電路圖，請設計其 Verilog HDL 電路模組。

The circuit diagram of a  $\bar{S}\bar{R}$ -Latch is shown in the following figure. Please write the Verilog circuit module for it.

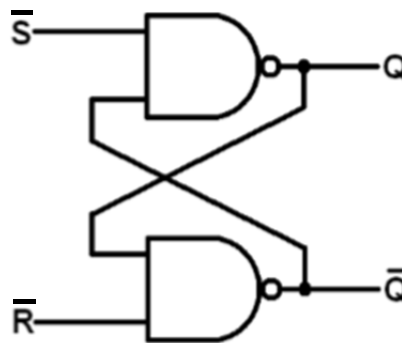


圖 1： $\bar{S}\bar{R}$ -Latch 的電路圖

Figure 1: The circuit diagram of an  $\bar{S}\bar{R}$ -Latch.

- i. 請根據上述電路圖(圖 1)，以 gate-level modeling 的方式撰寫其電路模組。假設每個 NAND gate 的 delay 為 2 ns。模組名稱與 port list 請訂為 `Lab3_SbRb_Latch_gatelevel(output Q, NQ, input Sb, Rb)`，檔案則請命名為 `Lab3_SbRb_Latch_gatelevel.v`。

According to the logic diagram shown in Figure 1, please write the Verilog circuit module in gate-level modeling. Assume that the delay of an NAND gate

is 2 ns. The circuit module and port list should be named as Lab3\_SbRb\_Latch\_gatelevel(output Q, NQ, input Sb, Rb), and its file should be named as Lab3\_SbRb\_Latch\_gatelevel.v.

- ii. 請撰寫此 $\bar{S}\bar{R}$ -Latch 之測試電路模組，必須至少包含下述指定之測資。請將此測試電路模組命名為 t\_Lab3\_SbRb\_Latch\_gatelevel，檔案則命名為 t\_Lab3\_SbRb\_Latch\_gatelevel.v。

Please write the testbench of the  $\bar{S}\bar{R}$ -Latch in which the test data shown in the following table must be included. The testbench module should be named as t\_Lab3\_SbRb\_Latch\_gatelevel, and its file should be named as t\_Lab3\_SbRb\_Latch\_gatelevel.v.

Time (ns)	Sb	Rb
0	1	0
10	1	1
20	0	1
30	1	1
40	0	0
50	1	1
60	1	0

- B. D-type Positive Edge Trigger Flip-Flop:** 下圖為一正緣觸發的 D-Flip-Flop，請設計其 Verilog HDL 電路模組。

The circuit diagram of a D-type positive-edge triggered Flip-Flop is shown in the following figure. Please design the Verilog circuit module for it.

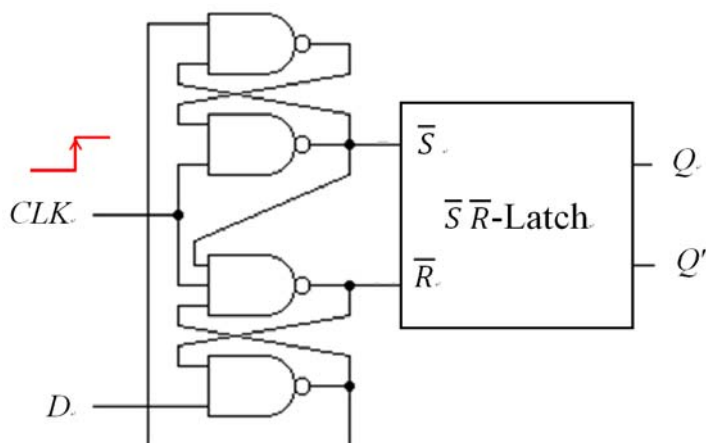


圖 2：正緣觸發的 D-Flip-Flop 電路圖

Figure 2: The circuit diagram of a positive-edge triggered D-Flip-Flop.

- i. 請根據上述電路圖(圖 2)，利用 A(i)的 module，以 gate-level modeling 的方式撰寫其電路模組。假設每個 NAND gate 的 delay 為 2 ns。模組名稱與 port list 請訂為 Lab3\_Pos\_Edge\_D\_FF\_gatelevel(output Q, NQ, input D, clock)，檔案

則請命名為 `Lab3_Pos_Edge_D_FF_gatelevel.v`。

According to the logic diagram shown in Figure 2, please write the Verilog circuit module in gate-level modeling by using the module in A(i). Assume that the delay of an NAND gate is 2 ns. The circuit module and port list should be named as `Lab3_Pos_Edge_D_FF_gatelevel(output Q, NQ, input D, clock)`, and its file should be named as `Lab3_Pos_Edge_D_FF_gatelevel.v`.

- ii. 請撰寫此 D-flip-flop 之測試電路模組，clock 之週期為 20 ns (10 ns 為 HIGH、10 ns 為 LOW)，且至少必須包含下述指定之測資。請將此測試電路模組命名為 `t_Lab3_Pos_Edge_D_FF_gatelevel`，檔案則命名為 `t_Lab3_Pos_Edge_D_FF_gatelevel.v`。

Please write the testbench of this D flip-flop in which the test data shown in the following table must be included. The period of the clock is 20 ns, HIGH for 10 ns and then LOW for 10 ns. The testbench should be named as `t_Lab3_Pos_Edge_D_FF_gatelevel`, and its file should be named as `t_Lab3_Pos_Edge_D_FF_gatelevel.v`.

Time(ns)	D
0	0
15	1
35	0
65	1
88	0
125	1
130	0

- C. Mealy-Type Synchronous Sequential Circuit:** 設計一個 Mealy-type 的同步順序電路，圖 3 為其狀態圖(state diagram)。

Design a Mealy-type synchronous sequential circuit of which the state diagram is shown in Figure 3.

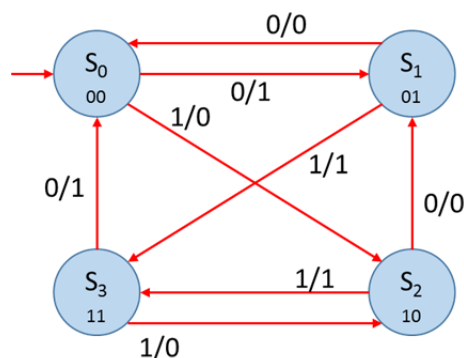


圖 3：Mealy-type 同步順序電路之狀態圖

Figure 3: The state diagram of a Mealy-type synchronous sequential circuit.

- i. 請根據此電路之狀態圖(圖 3)，以 State-diagram-based model 方式撰寫其 Verilog HDL 電路模組。各狀態之二元編碼為  $S_0 = 00$ ,  $S_1 = 01$ ,  $S_2 = 10$ ,  $S_3 = 11$ 。假設此電路圖有 reset 輸入訊號，此 reset 訊號為 Active LOW，可設定電路至初始狀態  $S_0$  (00)。模組名稱與 port list 請訂為 `Lab3_Mealy_state_diagram` (output `z`, input `x`, `clock`, `reset`)，檔案則請命名為 `Lab3_Mealy_state_diagram.v`。

According to the state diagram shown in Figure 3, write the Verilog circuit module for this synchronous sequential circuit by state-diagram-based model. The binary assignment of the states are  $S_0 = 00$ ,  $S_1 = 01$ ,  $S_2 = 10$ ,  $S_3 = 11$ . Assume that this circuit has an active-LOW *reset* signal which may reset the circuit to its initial state  $S_0$  (00). The circuit module and port list should be named as `Lab3_Mealy_state_diagram` (output `z`, input `x`, `clock`, `reset`), and its file should be named as `Lab3_Mealy_state_diagram.v`.

- ii. 完成此同步順序電路之設計，以 JK 正反器做為其儲存元件。根據推導出之電路圖，以 Structural model 方式撰寫其 Verilog HDL 電路模組。假設此電路圖有 reset 輸入訊號，可設定電路至初始狀態  $S_0$  (00)。模組名稱與 port list 請訂為 `Lab3_Mealy_structural` (output `z`, input `x`, `clock`, `reset`)，檔案則請命名為 `Lab3_Mealy_structural.v`。請注意，此電路模組中需要用到有 asynchronous reset (又稱 direct reset) 之 JK flip-flop 的電路模組，可自行撰寫或使用課本上之模組，檔案請命名為 `JK_ff_AR.v`。假設此 *reset* 訊號為 Active-LOW。

Complete the design of this synchronous sequential circuit by using JK flip-flops. According to the circuit diagram derived, write the Verilog circuit module for this circuit by structural model. Assume that the circuit can be reset to its initial state  $S_0$  (00) by input signal *reset*. The circuit module and port list should be named as `Lab3_Mealy_structural` (output `z`, input `x`, `clock`, `reset`), and its file should be named as `Lab3_Mealy_structural.v`. Note that this circuit module requires to instantiate the circuit module of a JK flip-flop with *asynchronous reset*, also called as *direct reset*. You may design the JK flip-flop module by yourself or apply the module provided in the textbook. The file of the JK flip-flop should be named as `JK_ff_AR.v`. Assume that the *reset* signal is active-LOW.

- iii. 請撰寫一測試模組來完整測試上述兩個電路模組。請將此測試模組命名為 `t_Lab3_Mealy`，檔案則請命名為 `t_Lab3_Mealy.v`。

Please write a testbench to test the two circuit modules designed above thoroughly. The testbench module should be named as `t_Lab3_Mealy`, and its file should be named as `t_Lab3_Mealy.v`.

**\* 注意事項：**

- 請用 ModelSim Student Edition 10.4a 做為開發環境。  
Develop your lab in ModelSim Student Edition 10.4.a.
- 請務必依照上述各項目之規定命名模組及檔案。  
Be sure to name the modules and files as described above.
- 禁止抄襲，違者(抄襲者與被抄襲者)以 0 分計算。  
Any assignment work by fraud will get a zero point.
- 助教會以其他測資去測試上述作業。  
TA will use similar testbench modules with different test data to verify the correctness of your design of the Verilog circuit modules.

### 3. 作業及 HDL 模組繳交(Hand in)

#### A. 作業報告繳交：word 檔，命名為 **Lab3\_學號\_姓名**

包含下列項目：

**Hand in a word file, named **Lab3\_StudentID\_Name**, including the following items:**

- (1) 2A 之模擬結果波形圖，並說明其模擬結果波形圖是否正確。(20%)  
Give the waveform of the simulation results in 2A, and explain whether it is correct or not.
- (2) 2B 之模擬結果波形圖，並說明其模擬結果波形圖是否正確。(20%)  
Give the waveform of the simulation results in 2B, and explain whether it is correct or not.
- (3) 敘述 2C 之 Mealy-type 同步順序電路之設計過程，以 JK 為儲存元件，推導出其電路圖。而後，列出 2C 之模擬結果波形圖，並說明其 testbench 如何設計、針對 input stimulus 預期之狀態轉換與輸出值為何、及 i. 和 ii. 兩種電路模組之模擬結果波形圖是否正確。(50%)  
Describe the design of the Mealy-type synchronous sequential circuit in 2C by using JK flip-flops based on the design procedure of synchronous sequential circuits. Then, give the waveform of the simulation results in 2C, explain how you design your testbench, show the state transitions and outputs for the input stimuli, and determine whether each of the two circuit modules designed by you is correct or not.
- (4) 心得與感想、及遭遇到的問題或困難 (10%)  
Describe what you have learned from this lab unit and discuss the problems or difficulties encountered in this lab.

#### B. Verilog modules 檔案繳交：8 files

**Hand in the following Verilog modules: 8 files**

Lab3\_SbRb\_Latch\_gatelevel.v 、  
t\_Lab3\_SbRb\_Latch\_gatelevel.v 、  
Lab3\_Pos\_Edge\_D\_FF\_gatelevel.v 、

t\_Lab3\_Pos\_Edge\_D\_FF\_gatelevel.v、  
Lab3\_Mealy\_state\_diagram、  
Lab3\_Mealy\_structural.v、  
JK\_ff\_AR.v、  
t\_Lab3\_Mealy.v

## 4. DEADLINE

- 本實驗單元為一人一組，作業請上傳至 E3 平台。

This lab unit is one student per group. Please upload your Lab Report (word file) and the corresponding HDL code (.v files) onto e-Campus platform.

- 作業繳交截止日期為 **2019/6/10 (一) 23:55**。不接受逾期繳交。

The deadline for handing in lab report and Verilog files is **2019/6/10 (Monday) 23:55. No late hand-in is allowed.**

- 請將上述作業報告及 Verilog 電路模組與測試模組檔案(.v)全部壓縮成一個 **zip 檔**或 **rar 檔**(禁止上傳其他檔案格式)，並以「**Lab3\_學號\_姓名**」的方式命名，如：「Lab3\_0416000\_王大明」。

Please compress the word file of lab report and the Verilog circuit modules and testbench described above all into one **zip** or **rar** file (other format is not accepted), and name the zip file as “**Lab3\_StudentID\_Name**”, for example, “Lab3\_0416000\_Kent Chang”

- 上機演示 Demo 時間暫定為 **2019/6/12 (三) 1:00PM~9:30PM**，之後會再發公告通知大家上網填寫 Demo 時間表。未繳交作業者，將不予 Demo;有繳交作業但未 Demo 者，亦不予計分。

The time for on-line demo is arranged at **2019/6/12 (Wed.) 1:00PM~9:30PM** tentatively, and we will send an announcement to inform you to fill the Demo schedule online. Those who have not hand-in their lab reports and Verilog files will not be able to demo their work.

- 程式碼請勿抄襲別人或讓別人抄襲，經查證後此次 lab 總分一律以 0 分計算。  
**Any assignment work by fraud will get a zero point**